

2SK2393

Silicon N Channel MOS FET

Application

High voltage / High speed power switching

Features

- Low on-resistance, High breakdown voltage
- High speed switching
- Low Drive Current
- No Secondary Breakdown
- Suitable for Switching regulator, Motor Control

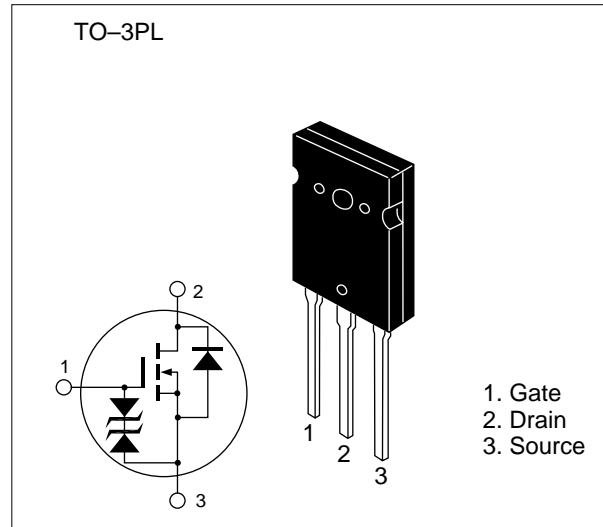


Table 1 Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	1500	V
Gate to source voltage	V_{GSS}	± 20	V
Drain current	I_D	8	A
Drain peak current	$I_{D(\text{pulse})}^*$	20	A
Body-drain diode reverse drain current	I_{DR}	8	A
Channel dissipation	P_{ch}^{**}	200	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

* $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

** Value at $T_c = 25^\circ\text{C}$

Table 2 Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	1500	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0^*$
Gate to source leak current	I_{GSS}	—	—	± 1	μA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	500	μA	$V_{DS} = 1200 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	4.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	1.9	2.8	Ω	$I_D = 4 \text{ A}$ $V_{GS} = 15 \text{ V}^*$
Forward transfer admittance	$ y_{fs} $	1.8	3.0	—	S	$I_D = 4 \text{ A}$ $V_{DS} = 20 \text{ V}^*$
Input capacitance	C_{iss}	—	4370	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	C_{oss}	—	560	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	200	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	75	—	ns	$I_D = 4 \text{ A}$
Rise time	t_r	—	180	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	260	—	ns	$R_L = 7.5 \Omega$
Fall time	t_f	—	125	—	ns	
Body-drain diode forward voltage	V_{DF}	—	0.9	—	V	$I_F = 8 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery time	t_{rr}	—	6.5	—	μs	$I_F = 8 \text{ A}, V_{GS} = 0,$ $di_F / dt = 100 \text{ A} / \mu\text{s}$

* Pulse Test

